

| Color | Type | Technology | Angle of Half Intensity $\pm\varphi$ |
|------------|-----------|--------------------|-----------------------------------------|
| Red | TLWR76.. | AllnGaP on GaAs | 30° |
| Yellow | TLWY76.. | AllnGaP on GaAs | 30° |
| True Green | TLWTG76.. | InGaN on SiC | 30° |
| Blue Green | TLWBG76.. | InGaN on SiC | 30° |
| Blue | TLWB76.. | InGaN on SiC | 30° |
| White | TLWW76.. | InGaN / YAG on SiC | 30° |

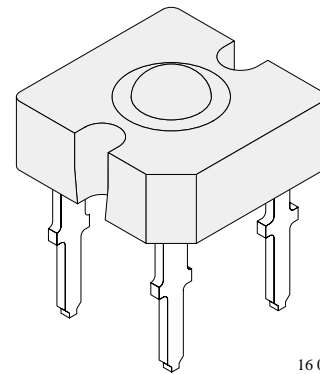
Description

The TELUX™ series is a clear, non diffused LED for high end applications where supreme luminous flux is required.

It is designed in an industry standard 7.62 mm square package utilizing highly developed (AS) AllnGaP and InGaN technologies.

The supreme heat dissipation of TELUX™ allows applications at high ambient temperatures.

All packing units are binned for luminous flux and color to achieve best homogenous light appearance in application.



16 012

Features

- Utilizing (AS) AllnGaP and InGaN technologies
- High luminous flux
- Supreme heat dissipation: R_{thJP} is 90 K/W
- High operating temperature: T_j up to + 125 °C
- Type TLWR meets SAE and ECE color requirements
- Packed in tubes for automatic insertion
- Luminous flux and color categorized for each tube
- Small mechanical tolerances allow precise usage of external reflectors or lightguides
- TLWR types additionally forward voltage categorized

Applications

Exterior lighting
 Dashboard illumination
 Tail-, Stop – and Turn Signals of motor vehicles
 Replaces incandescent lamps
 Traffic signals and signs

Absolute Maximum Ratings

$T_{amb} = 25^{\circ}\text{C}$, unless otherwise specified

TLWR76.. , TLWY76..

| Parameter | Test Conditions | Type | Symbol | Value | Unit |
|-------------------------------------|--------------------------------------------------------------------------------------------------|----------|------------|-------------|--------------------|
| Reverse voltage | $I_R = 10\mu\text{A}$ | TLWR76.. | V_R | 10 | V |
| DC forward current | $T_{amb} \leq 85^{\circ}\text{C}$ | | I_F | 70 | mA |
| Surge forward current | $t_p \leq 10\ \mu\text{s}$ | TLWY76.. | I_{FSM} | 1 | A |
| Power dissipation | $T_{amb} \leq 85^{\circ}\text{C}$ | | P_V | 187 | mW |
| Junction temperature | | | T_j | 125 | $^{\circ}\text{C}$ |
| Operating temperature range | | | T_{amb} | -40 to +110 | $^{\circ}\text{C}$ |
| Storage temperature range | | | T_{stg} | -55 to +110 | $^{\circ}\text{C}$ |
| Soldering temperature | $t \leq 5\ \text{s}$, 1.5 mm from body preheat temperature 100 $^{\circ}\text{C}$ /30sec. | | T_{sd} | 260 | $^{\circ}\text{C}$ |
| Thermal resistance junction/ambient | with cathode heatsink of 70 mm ² | | R_{thJA} | 200 | K/W |

$T_{amb} = 25^{\circ}\text{C}$, unless otherwise specified

TLWTG76.. , TLWBG76.. , TLWB76.. , TLWW76..

| Parameter | Test Conditions | Type | Symbol | Value | Unit |
|-------------------------------------|--------------------------------------------------------------------------------------------------|-----------|------------|-------------|--------------------|
| Reverse voltage | $I_R = 10\mu\text{A}$ | TLWTG76.. | V_R | 5 | V |
| DC forward current | $T_{amb} \leq 50^{\circ}\text{C}$ | TLWBG76.. | I_F | 50 | mA |
| Surge forward current | $t_p \leq 10\ \mu\text{s}$ | TLWB76.. | | | |
| Power dissipation | $T_{amb} \leq 50^{\circ}\text{C}$ | TLWW76.. | I_{FSM} | 0.1 | A |
| Power dissipation | $T_{amb} \leq 50^{\circ}\text{C}$ | TLWTG76.. | P_V | 230 | mW |
| | | TLWBG76.. | | | |
| | | TLWB76.. | | | |
| | | TLWW76.. | P_V | 255 | mW |
| Junction temperature | | | T_j | 100 | $^{\circ}\text{C}$ |
| Operating temperature range | | | T_{amb} | -40 to +100 | $^{\circ}\text{C}$ |
| Storage temperature range | | | T_{stg} | -55 to +100 | $^{\circ}\text{C}$ |
| Soldering temperature | $t \leq 5\ \text{s}$, 1.5 mm from body preheat temperature 100 $^{\circ}\text{C}$ /30sec. | | T_{sd} | 260 | $^{\circ}\text{C}$ |
| Thermal resistance junction/ambient | with cathode heatsink of 70 mm ² | | R_{thJA} | 200 | K/W |

**Optical and Electrical Characteristics** $T_{amb} = 25^{\circ}\text{C}$, unless otherwise specified**Red (TLWR76..)**

| Parameter | Test Conditions | Type | Symbol | Min | Typ | Max | Unit |
|-----------------------------------|-----------------------------------------------------------|------|---------------|------|----------|------|-------------|
| Total flux | $I_F = 70\text{ mA}$, $R_{thJA} = 200^{\circ}\text{K/W}$ | | ϕ_V | 1500 | 2100 | 3000 | mlm |
| Luminous intensity/ Total flux | | | I_V/ϕ_V | | 0.8 | | mcd/ mlm |
| Dominant wavelength | | | λ_d | 611 | 616 | 634 | nm |
| Peak wavelength | | | λ_p | | 624 | | nm |
| Angle of half intensity | | | ϕ | | ± 30 | | deg |
| Total included angle | 90 % of Total Flux Captured | | $\phi_{0.9V}$ | | 75 | | deg |
| Forward voltage | $I_F = 70\text{ mA}$, $R_{thJA} = 200^{\circ}\text{K/W}$ | | V_F | 1.83 | 2.2 | 2.67 | V |
| Reverse voltage | $I_R = 10\ \mu\text{A}$ | | V_R | 10 | 20 | | V |
| Junction capacitance | $V_R = 0$, $f = 1\text{ MHz}$ | | C_j | | 17 | | pF |

Yellow (TLWY76..)

| Parameter | Test Conditions | Type | Symbol | Min | Typ | Max | Unit |
|-----------------------------------|-----------------------------------------------------------|------|---------------|------|----------|------|-------------|
| Total flux | $I_F = 70\text{ mA}$, $R_{thJA} = 200^{\circ}\text{K/W}$ | | ϕ_V | 1000 | 1400 | 2400 | mlm |
| Luminous intensity/ Total flux | | | I_V/ϕ_V | | 0.8 | | mcd/ mlm |
| Dominant wavelength | | | λ_d | 585 | 590 | 597 | nm |
| Peak wavelength | | | λ_p | | 594 | | nm |
| Angle of half intensity | | | ϕ | | ± 30 | | deg |
| Total included angle | 90 % of Total Flux Captured | | $\phi_{0.9V}$ | | 75 | | deg |
| Forward voltage | $I_F = 70\text{ mA}$, $R_{thJA} = 200^{\circ}\text{K/W}$ | | V_F | 1.83 | 2.1 | 2.67 | V |
| Reverse voltage | $I_R = 10\ \mu\text{A}$ | | V_R | 10 | 15 | | V |
| Junction capacitance | $V_R = 0$, $f = 1\text{ MHz}$ | | C_j | | 32 | | pF |

True Green (TLWTG76..)

| Parameter | Test Conditions | Type | Symbol | Min | Typ | Max | Unit |
|-----------------------------------|-----------------------------------------------------------|------|---------------|-----|----------|------|-------------|
| Total flux | $I_F = 50\text{ mA}$, $R_{thJA} = 200^{\circ}\text{K/W}$ | | ϕ_V | 630 | 900 | 1800 | mlm |
| Luminous intensity/ Total flux | | | I_V/ϕ_V | | 0.8 | | mcd/ mlm |
| Dominant wavelength | | | λ_d | 509 | 521 | 529 | nm |
| Peak wavelength | | | λ_p | | 520 | | nm |
| Angle of half intensity | | | ϕ | | ± 30 | | deg |
| Total included angle | 90 % of Total Flux Captured | | $\phi_{0.9V}$ | | 75 | | deg |
| Forward voltage | $I_F = 50\text{ mA}$, $R_{thJA} = 200^{\circ}\text{K/W}$ | | V_F | | 4.2 | 4.7 | V |
| Reverse voltage | $I_R = 10\ \mu\text{A}$ | | V_R | 5 | 10 | | V |
| Junction capacitance | $V_R = 0$, $f = 1\text{ MHz}$ | | C_j | | 50 | | pF |

Blue Green (TLWBG76..)

| Parameter | Test Conditions | Type | Symbol | Min | Typ | Max | Unit |
|-----------------------------------|----------------------------------------------------------------|------|---------------|-----|----------|------|-------------|
| Total flux | $I_F = 50 \text{ mA}, R_{thJA} = 200 \text{ }^\circ\text{K/W}$ | | ϕ_V | 400 | 700 | 1250 | mlm |
| Luminous intensity/ Total flux | | | I_V/ϕ_V | | 0.8 | | mcd/ mlm |
| Dominant wavelength | | | λ_d | 492 | 505 | 510 | nm |
| Peak wavelength | | | λ_p | | 503 | | nm |
| Angle of half intensity | | | ϕ | | ± 30 | | deg |
| Total included angle | 90 % of Total Flux Captured | | $\phi_{0.9V}$ | | 75 | | deg |
| Forward voltage | $I_F = 50 \text{ mA}, R_{thJA} = 200 \text{ }^\circ\text{K/W}$ | | V_F | | 4.2 | 4.7 | V |
| Reverse voltage | $I_R = 10 \text{ } \mu\text{A}$ | | V_R | 5 | 10 | | V |
| Junction capacitance | $V_R = 0, f = 1 \text{ MHz}$ | | C_j | | 50 | | pF |

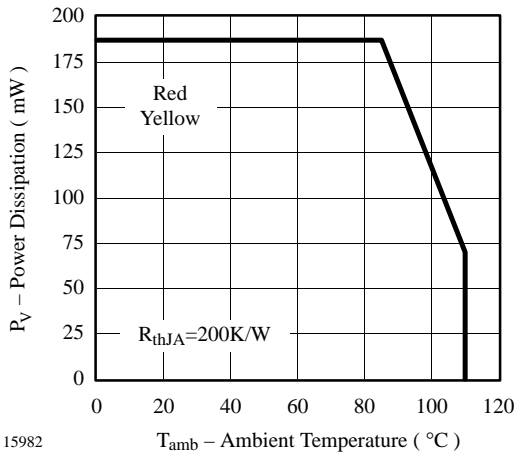
Blue (TLWB76..)

| Parameter | Test Conditions | Type | Symbol | Min | Typ | Max | Unit |
|-----------------------------------|----------------------------------------------------------------|------|---------------|-----|----------|-----|-------------|
| Total flux | $I_F = 50 \text{ mA}, R_{thJA} = 200 \text{ }^\circ\text{K/W}$ | | ϕ_V | 200 | 330 | 630 | mlm |
| Luminous intensity/ Total flux | | | I_V/ϕ_V | | 0.8 | | mcd/ mlm |
| Dominant wavelength | | | λ_d | 462 | 470 | 476 | nm |
| Peak wavelength | | | λ_p | | 465 | | nm |
| Angle of half intensity | | | ϕ | | ± 30 | | deg |
| Total included angle | 90 % of Total Flux Captured | | $\phi_{0.9V}$ | | 75 | | deg |
| Forward voltage | $I_F = 50 \text{ mA}, R_{thJA} = 200 \text{ }^\circ\text{K/W}$ | | V_F | | 4.3 | 4.7 | V |
| Reverse voltage | $I_R = 10 \text{ } \mu\text{A}$ | | V_R | 5 | 10 | | V |
| Junction capacitance | $V_R = 0, f = 1 \text{ MHz}$ | | C_j | | 50 | | pF |

White (TLWW76..)

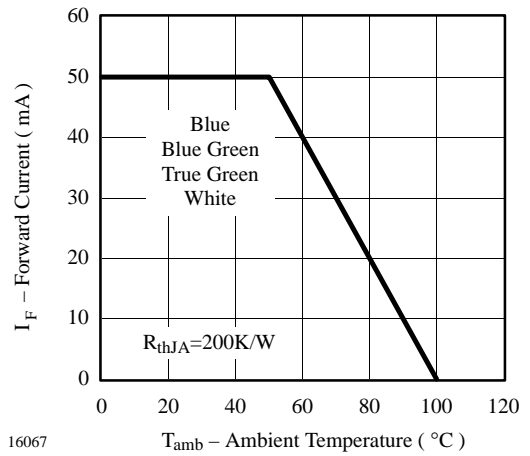
| Parameter | Test Conditions | Type | Symbol | Min | Typ | Max | Unit |
|-----------------------------------|----------------------------------------------------------------|-----------------------------|--------------|---------------|----------|------|-------------|
| Total flux | $I_F = 50 \text{ mA}, R_{thJA} = 200 \text{ }^\circ\text{K/W}$ | | ϕ_V | 400 | 650 | 1250 | mlm |
| Luminous intensity/ Total flux | | | I_V/ϕ_V | | 0.8 | | mcd/ mlm |
| Color temperature | | | T_K | | 5500 | | K |
| Angle of half intensity | | | ϕ | | ± 30 | | deg |
| Total included angle | | 90 % of Total Flux Captured | | $\phi_{0.9V}$ | | 75 | |
| Forward voltage | $I_F = 50 \text{ mA}, R_{thJA} = 200 \text{ }^\circ\text{K/W}$ | | V_F | | 4.3 | 5.1 | V |
| Reverse voltage | $I_R = 10 \text{ } \mu\text{A}$ | | V_R | 5 | 10 | | V |
| Junction capacitance | $V_R = 0, f = 1 \text{ MHz}$ | | C_j | | 50 | | pF |

Typical Characteristics ($T_{amb} = 25^{\circ}\text{C}$, unless otherwise specified)



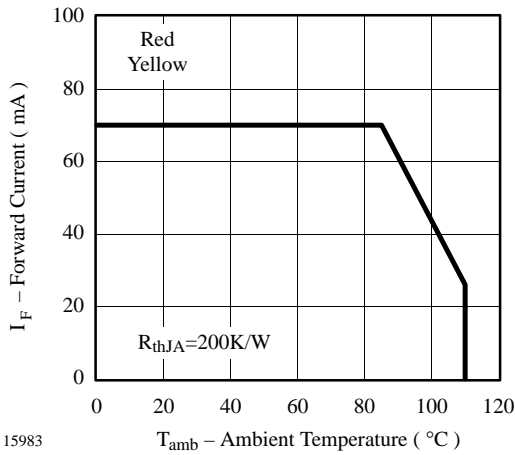
15982

Figure 1 Power Dissipation vs. Ambient Temperature



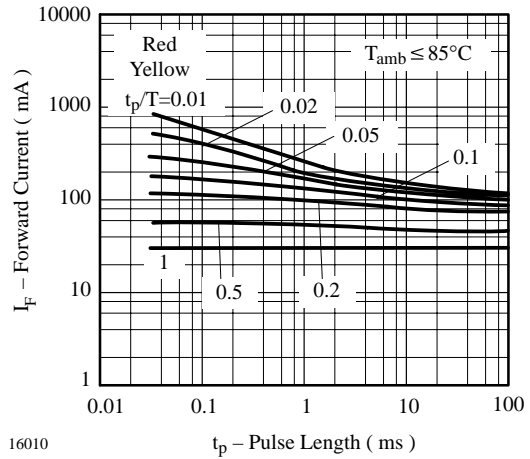
16067

Figure 4 Forward Current vs. Ambient Temperature



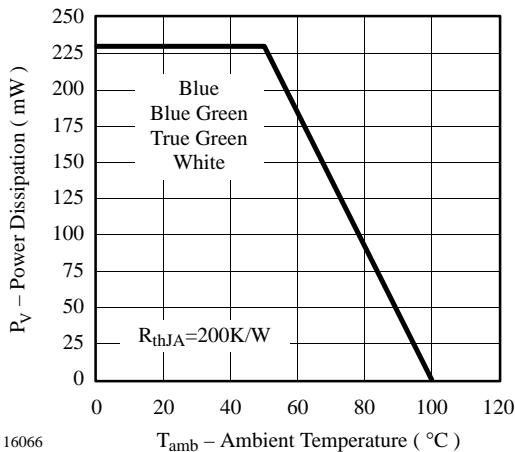
15983

Figure 2 Forward Current vs. Ambient Temperature



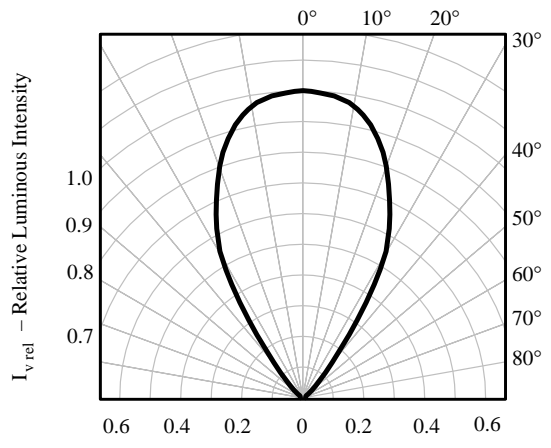
16010

Figure 5 Forward Current vs. Pulse Length



16066

Figure 3 Power Dissipation vs. Ambient Temperature



16006

Figure 6 Rel. Luminous Intensity vs. Angular Displacement

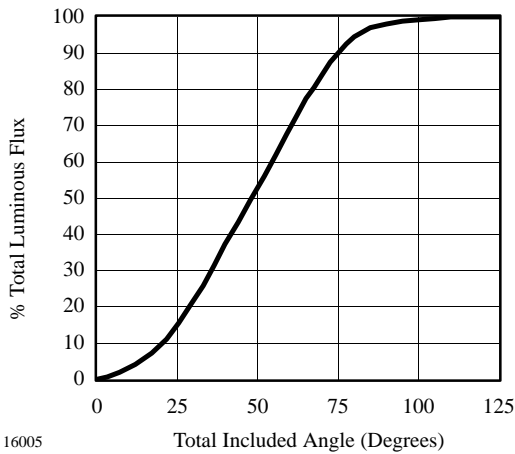


Figure 7 Percentage Total Luminous Flux vs. Total Included Angle (Degrees)

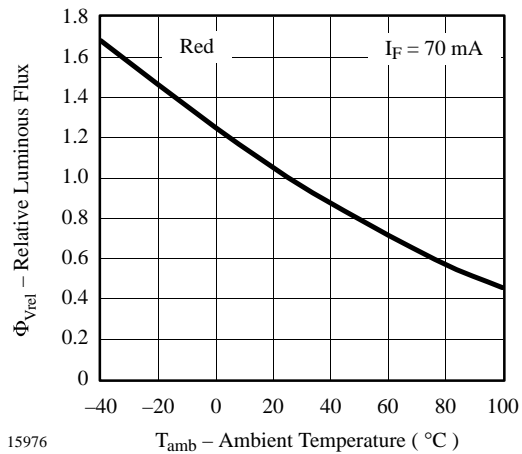


Figure 10 Rel. Luminous Flux vs. Ambient Temperature

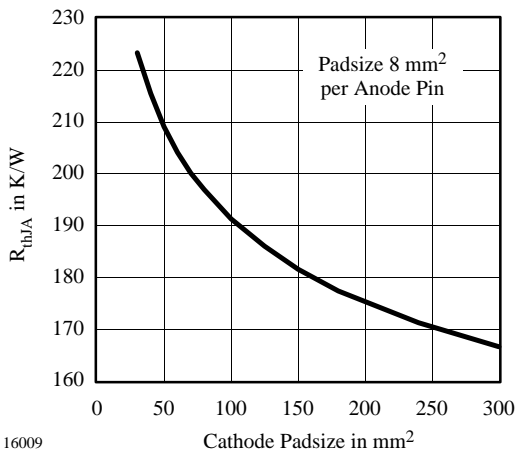


Figure 8 Thermal Resistance Junction Ambient vs. Cathode Padsizes

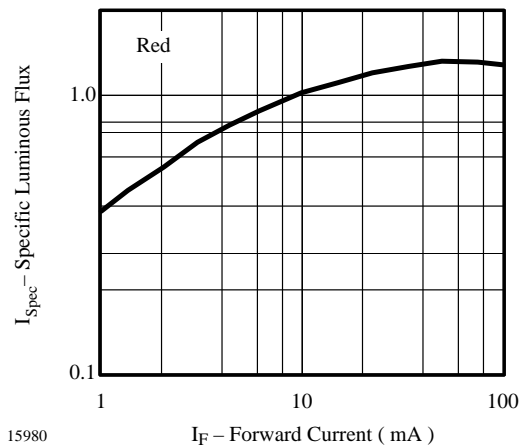


Figure 11 Specific Luminous Flux vs. Forward Current

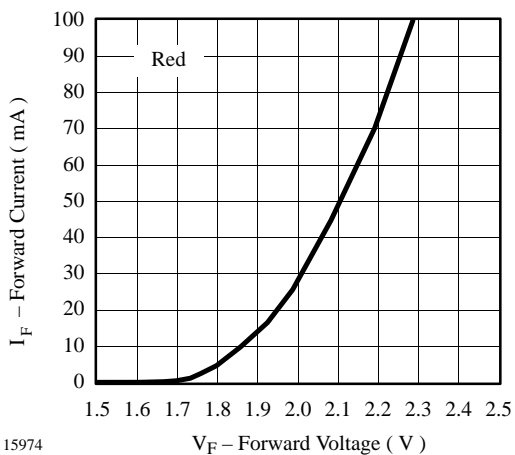


Figure 9 Forward Current vs. Forward Voltage

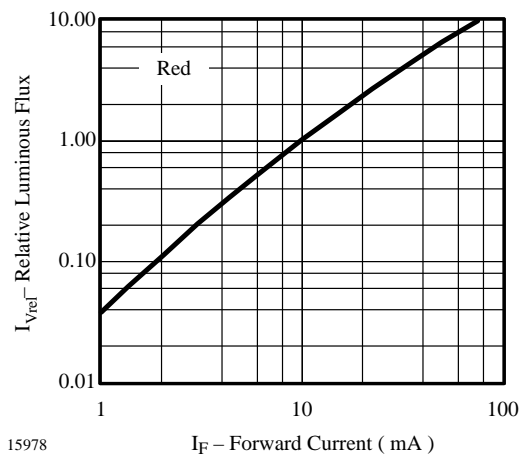


Figure 12 Relative Luminous Flux vs. Forward Current

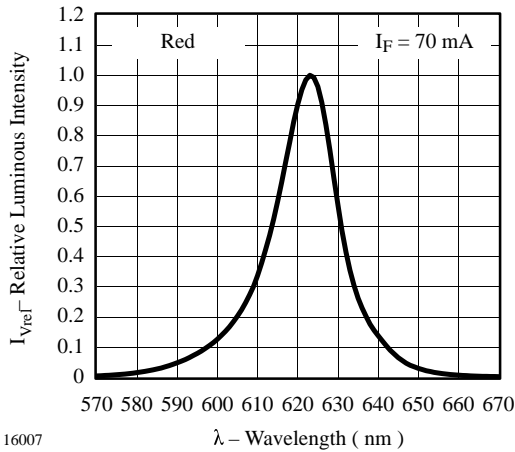


Figure 13 Relative Luminous Intensity vs. Wavelength

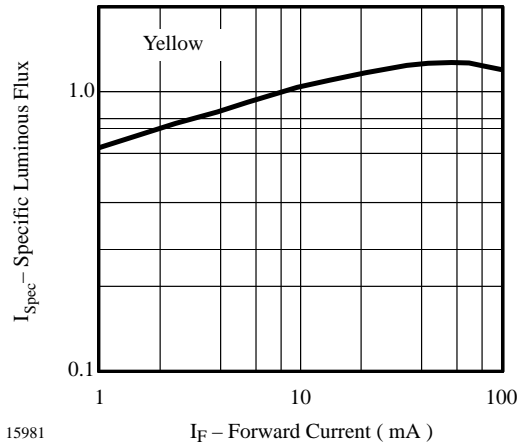


Figure 16 Specific Luminous Flux vs. Forward Current

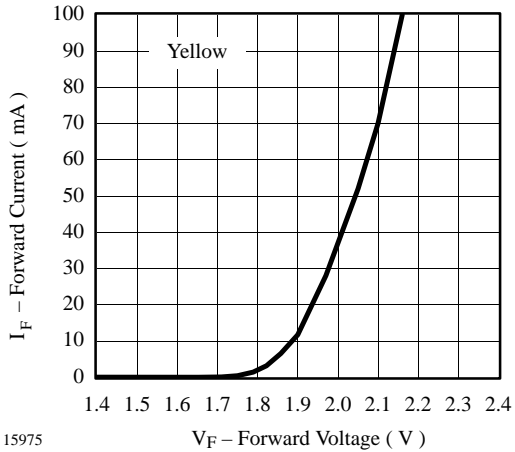


Figure 14 Forward Current vs. Forward Voltage

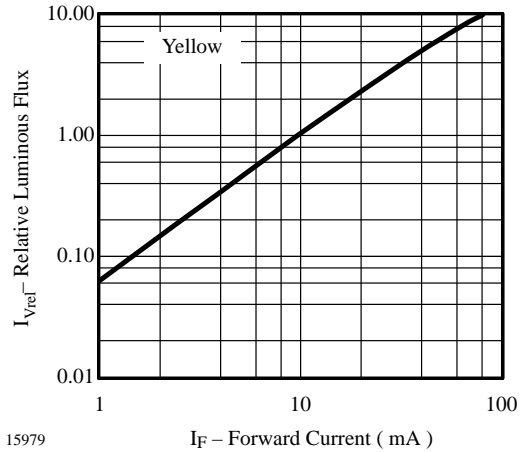


Figure 17 Relative Luminous Flux vs. Forward Current

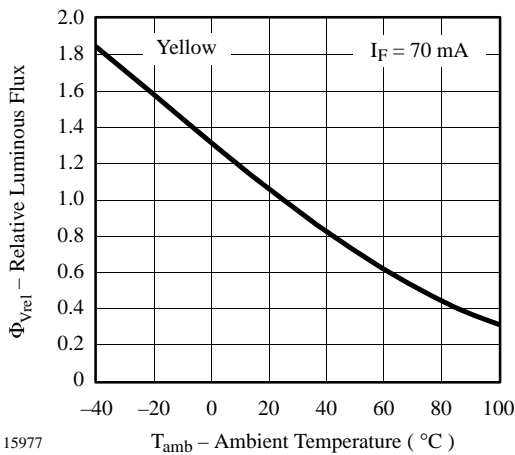


Figure 15 Rel. Luminous Flux vs. Ambient Temperature

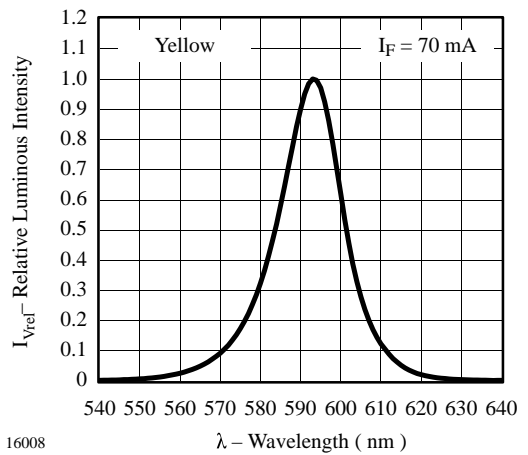


Figure 18 Relative Luminous Intensity vs. Wavelength

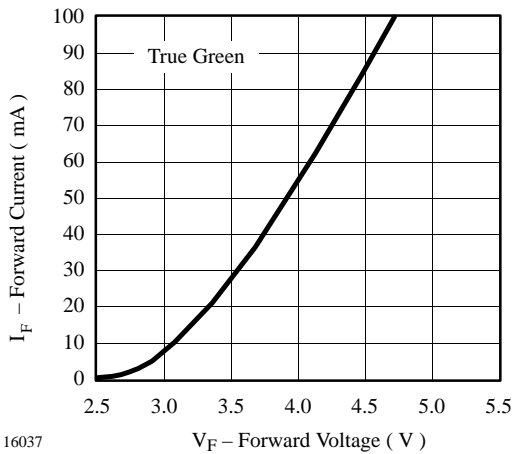


Figure 19 Forward Current vs. Forward Voltage

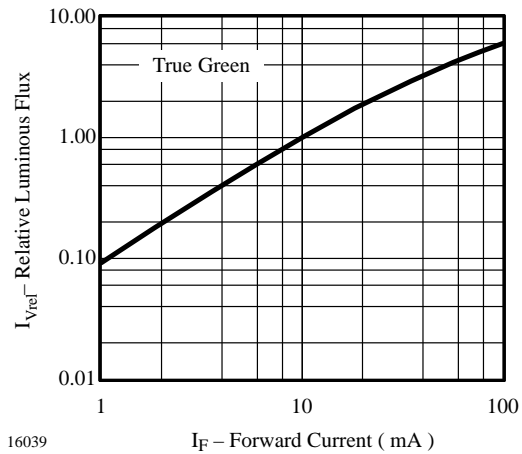


Figure 22 Relative Luminous Flux vs. Forward Current

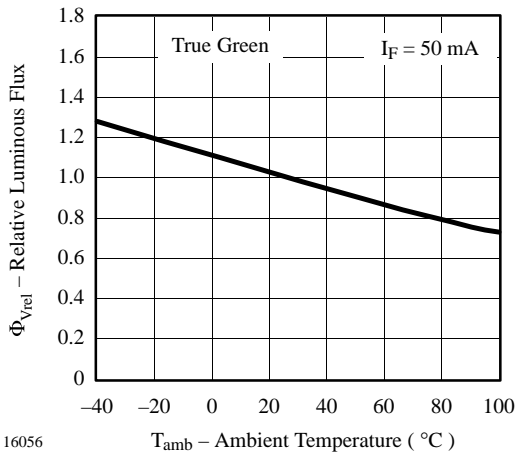


Figure 20 Rel. Luminous Flux vs. Ambient Temperature

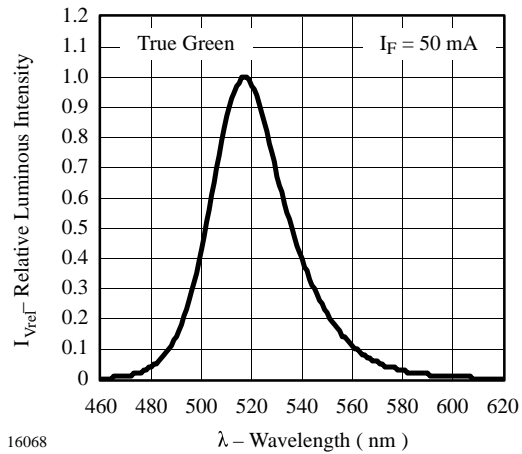


Figure 23 Relative Luminous Intensity vs. Wavelength

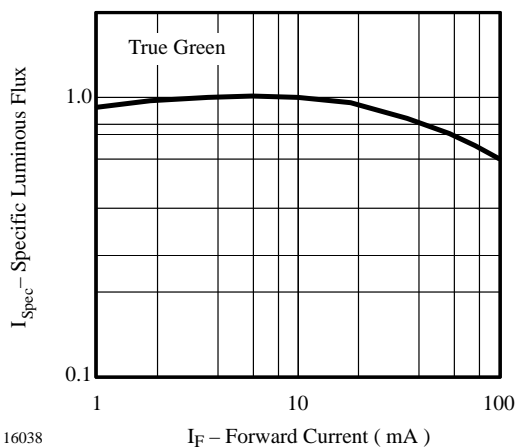


Figure 21 RSpecific Luminous Flux vs. Forward Current

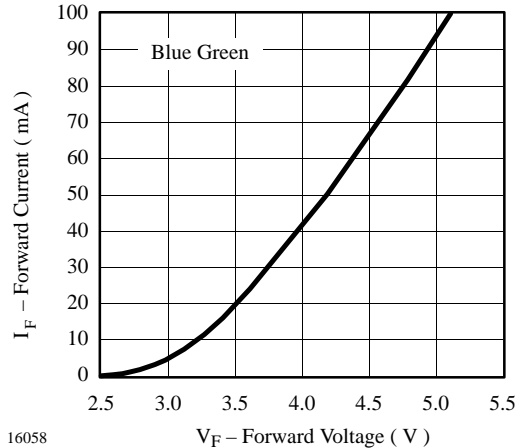


Figure 24 Forward Current vs. Forward Voltage

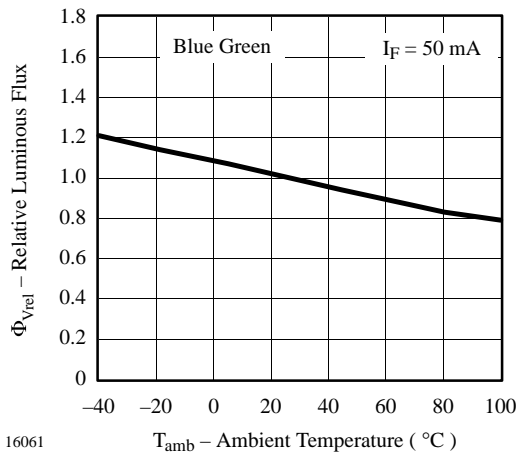


Figure 25 Rel. Luminous Flux vs. Ambient Temperature

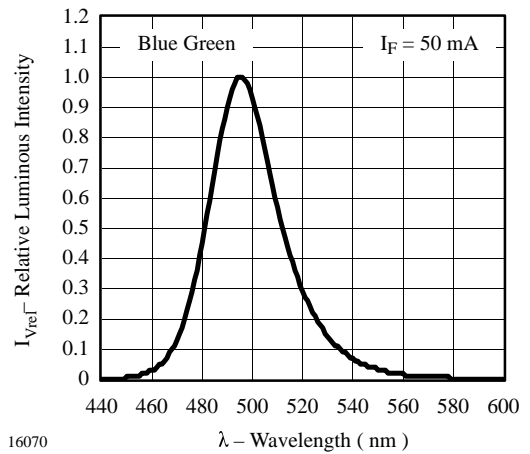


Figure 28 Relative Luminous Intensity vs. Wavelength

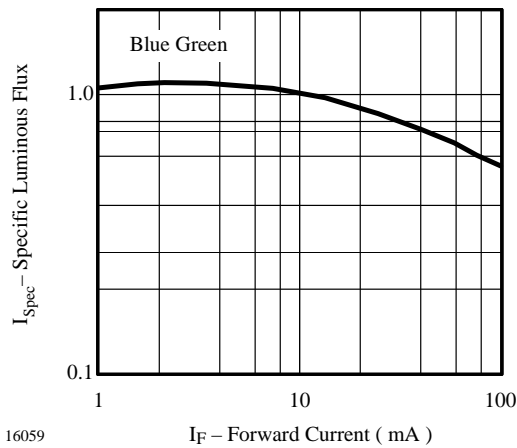


Figure 26 Specific Luminous Flux vs. Forward Current

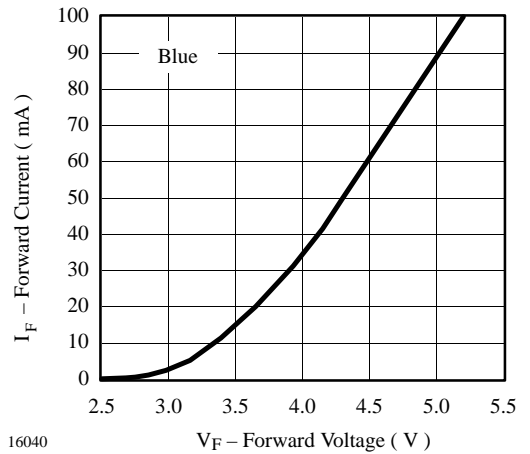


Figure 29 Forward Current vs. Forward Voltage

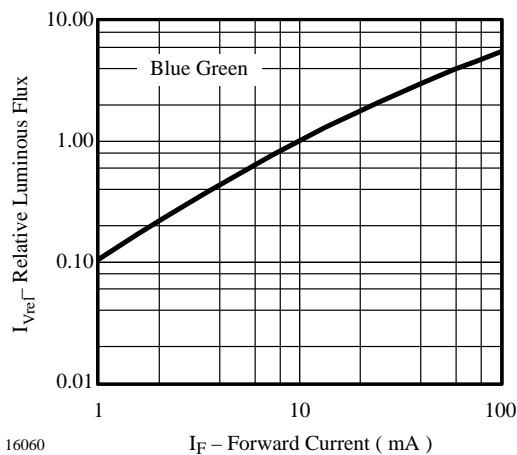


Figure 27 Relative Luminous Flux vs. Forward Current

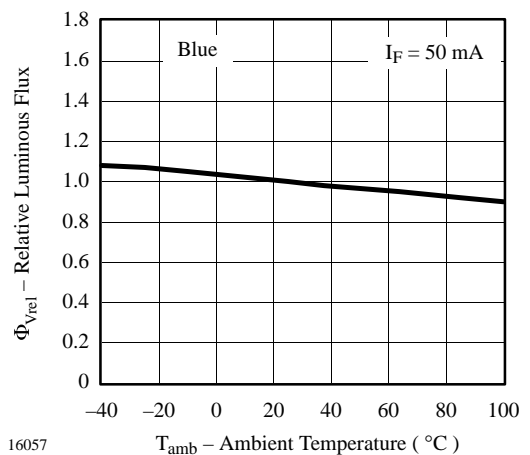
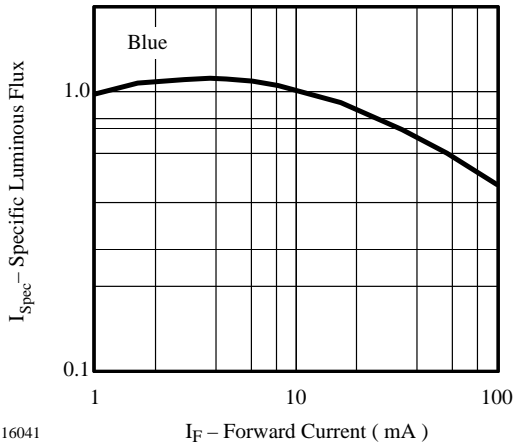
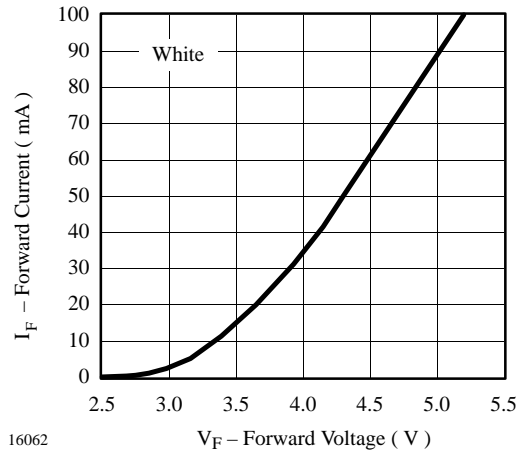


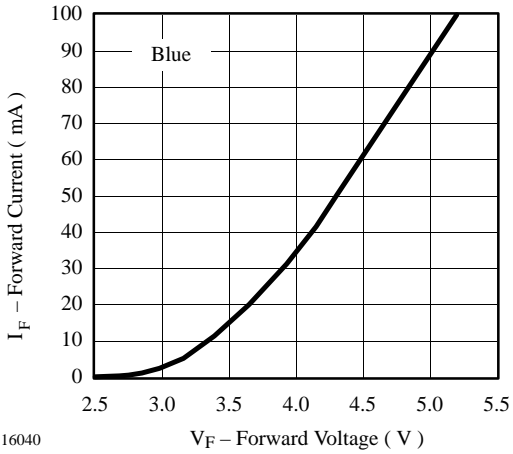
Figure 30 Rel. Luminous Flux vs. Ambient Temperature



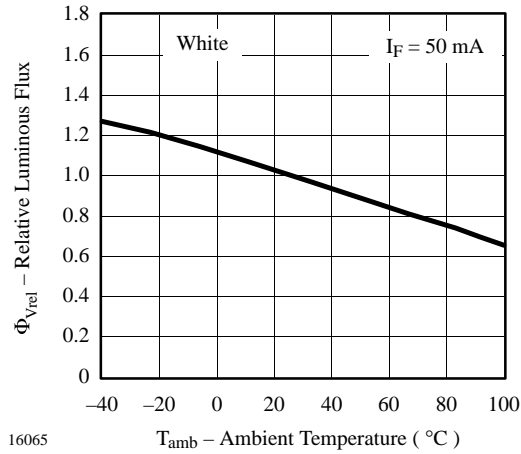
16041 I_{Spec} – Specific Luminous Flux
 I_F – Forward Current (mA)
 Figure 31 Specific Luminous Flux vs. Forward Current



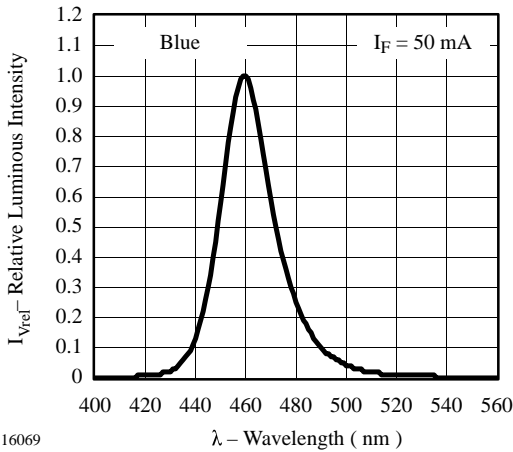
16062 I_F – Forward Current (mA)
 V_F – Forward Voltage (V)
 Figure 34 Forward Current vs. Forward Voltage



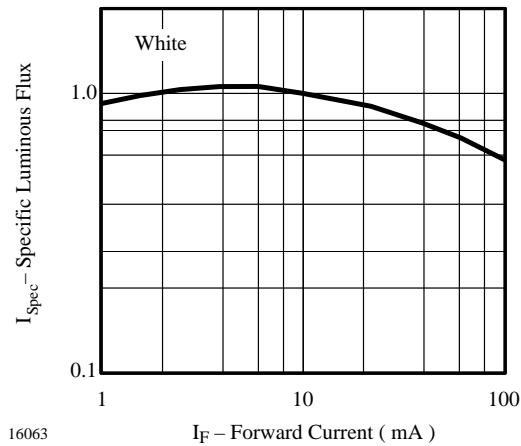
16040 I_F – Forward Current (mA)
 V_F – Forward Voltage (V)
 Figure 32 Forward Current vs. Forward Voltage



16065 Φ_{Vrel} – Relative Luminous Flux
 T_{amb} – Ambient Temperature (°C)
 $I_F = 50$ mA
 Figure 35 Rel. Luminous Flux vs. Ambient Temperature



16069 I_{Vrel} – Relative Luminous Intensity
 λ – Wavelength (nm)
 $I_F = 50$ mA
 Figure 33 Relative Luminous Intensity vs. Wavelength



16063 I_{Spec} – Specific Luminous Flux
 I_F – Forward Current (mA)
 Figure 36 Specific Luminous Flux vs. Forward Current

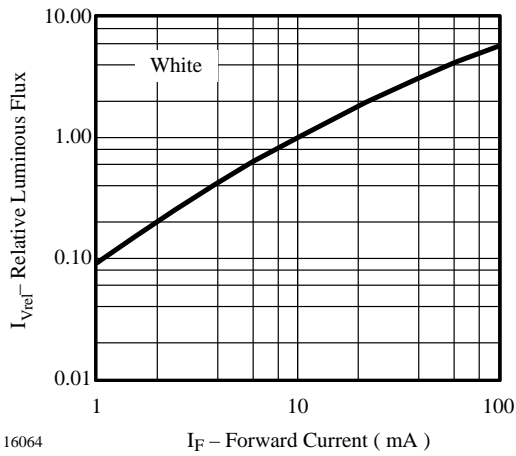


Figure 37 Rel. Luminous Flux vs. Ambient Temperature

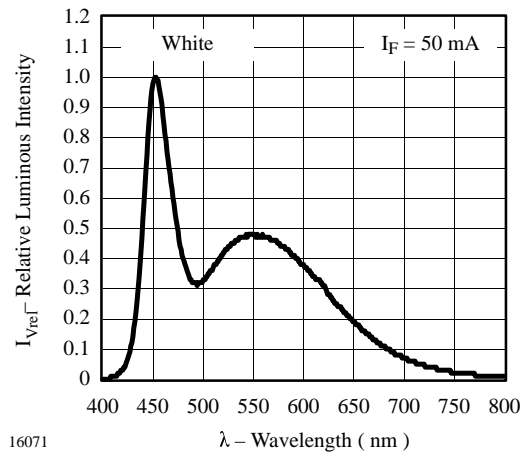
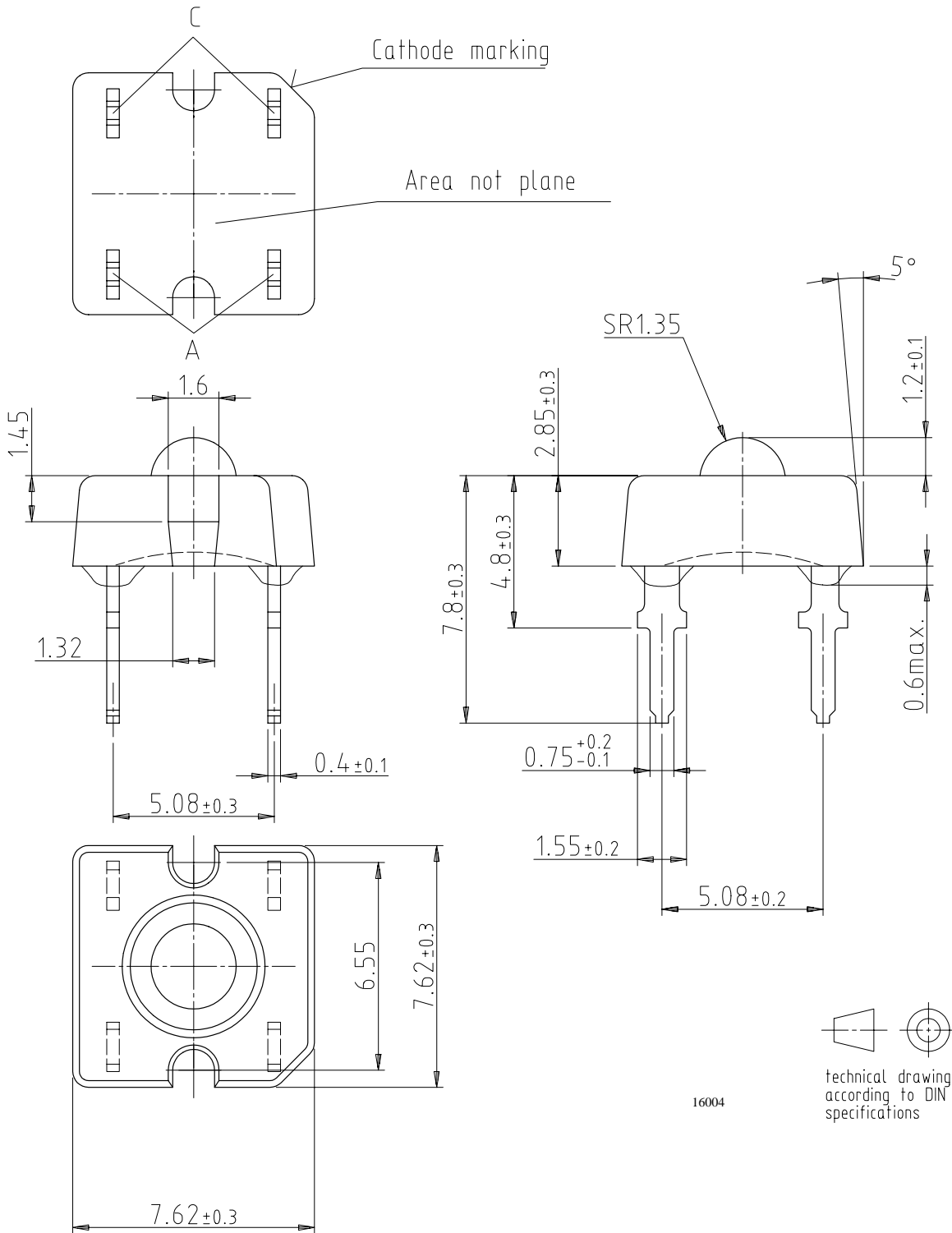


Figure 38 Specific Luminous Flux vs. Forward Current

Dimensions in mm



16004

technical drawings according to DIN specifications



Ozone Depleting Substances Policy Statement

It is the policy of **Vishay Semiconductor GmbH** to

1. Meet all present and future national and international statutory requirements.
2. Regularly and continuously improve the performance of our products, processes, distribution and operating systems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

It is particular concern to control or eliminate releases of those substances into the atmosphere which are known as ozone depleting substances (ODSs).

The Montreal Protocol (1987) and its London Amendments (1990) intend to severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.

Vishay Semiconductor GmbH has been able to use its policy of continuous improvements to eliminate the use of ODSs listed in the following documents.

1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively
2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA
3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

Vishay Semiconductor GmbH can certify that our semiconductors are not manufactured with ozone depleting substances and do not contain such substances.

We reserve the right to make changes to improve technical design and may do so without further notice.

Parameters can vary in different applications. All operating parameters must be validated for each customer application by the customer. Should the buyer use Vishay-Telefunken products for any unintended or unauthorized application, the buyer shall indemnify Vishay-Telefunken against all claims, costs, damages, and expenses, arising out of, directly or indirectly, any claim of personal damage, injury or death associated with such unintended or unauthorized use.

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